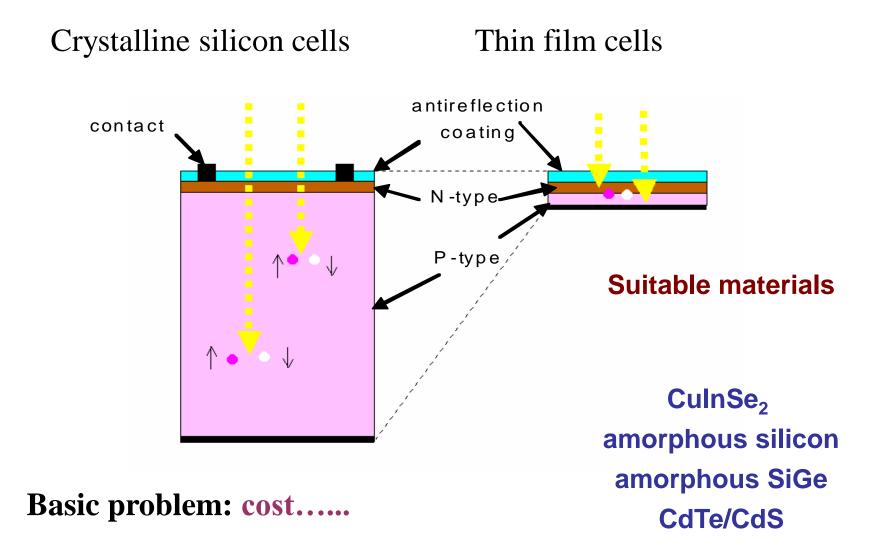
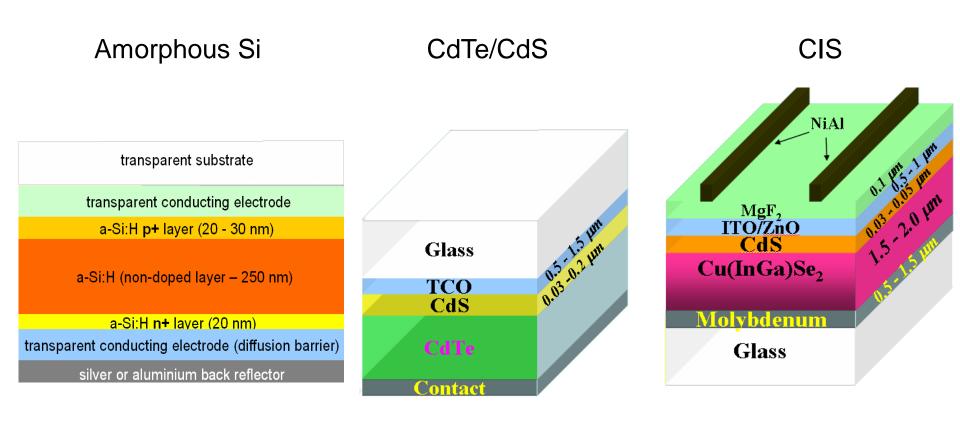
Thin film solar cells

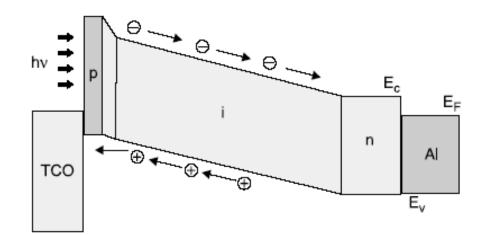
Basic types of solar cells:





Market share (2011) :

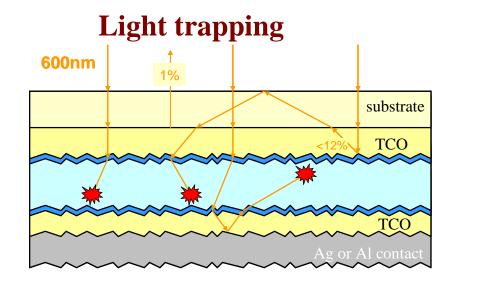
4.7% 5.7% 0.5%

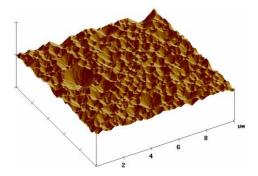


TCO:

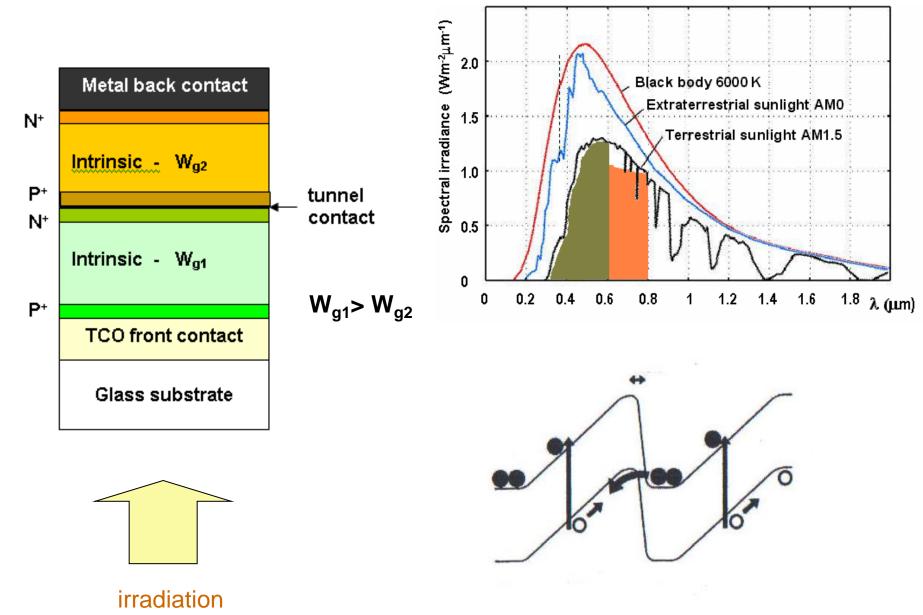
- SnO₂
- ITO (indium-tin oxide)

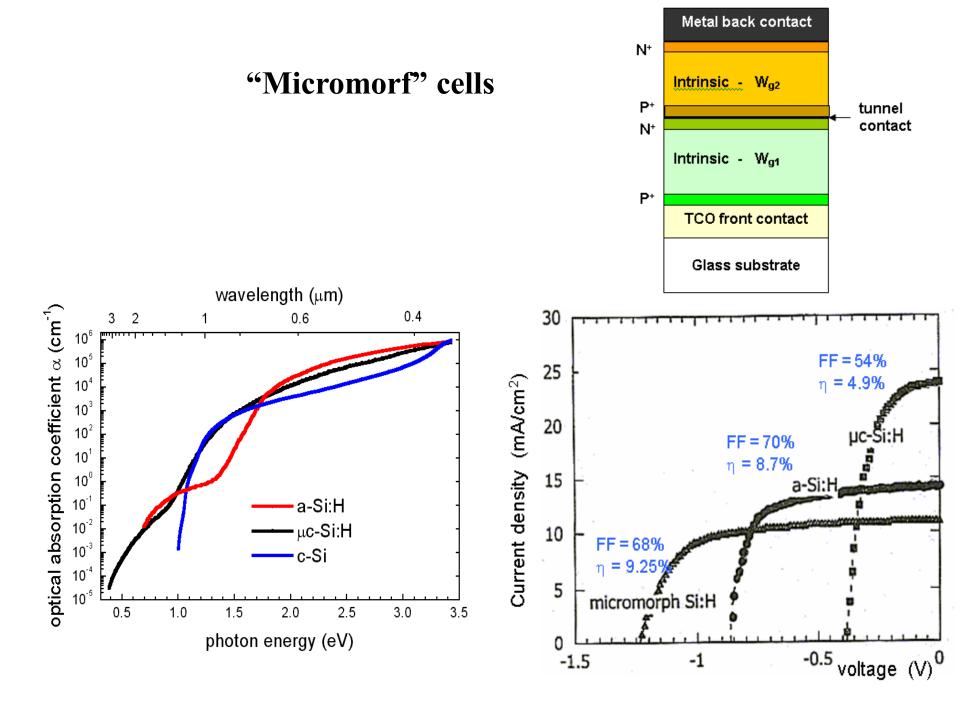
• ZnO





Tandem cells

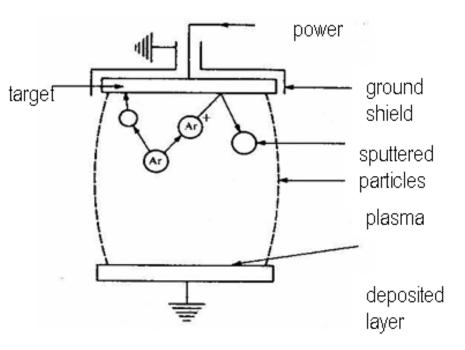




Thin film solar cell technology

A) Vacuum deposition

Filament evaporation Electron-beam evaporation Flash evaporation Sputtering



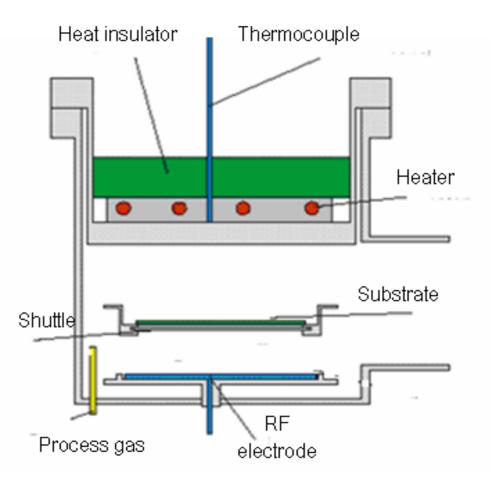
B) CVD (Chemical vapour deposition) technique

CVD technology is the formation of a stable compound on a heated substrate by the thermal reaction or decomposition of gaseous compounds

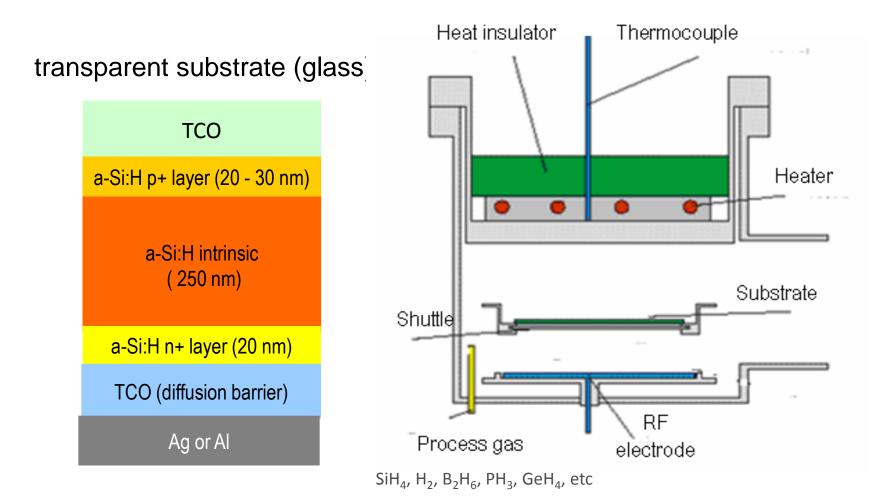
- Deposition of silicon nitride $3SiH_4 + 3NH_3 \rightarrow Si_3N_4 + 12H_2$
- Deposition of polysilicon layers $SiH_4 \rightarrow Si + 2H_2$
- Reaction chamber
- Gas control section
- Timing and sequence control
- Heat source for substrates
- Effective handling

Plasma enhanced CVD (PECVD)

- RF electrode and substrate create the capacitor structure
- In this space the plasma and incorporated deposition of material on substrate takes place

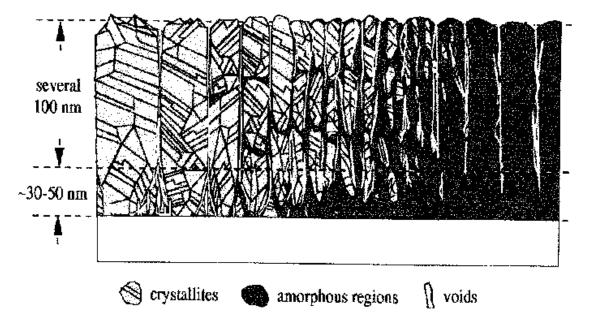


Amorphous (microcrystalline) silicon solar cells



The deposited layer structure depends on the gas composition and substrate temperature

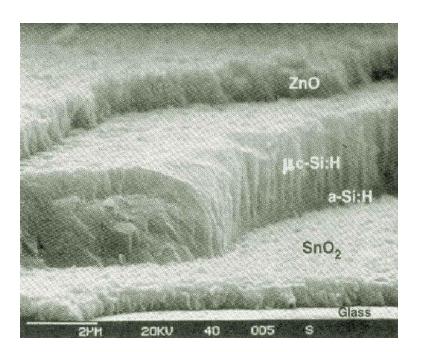
150 – 350°C

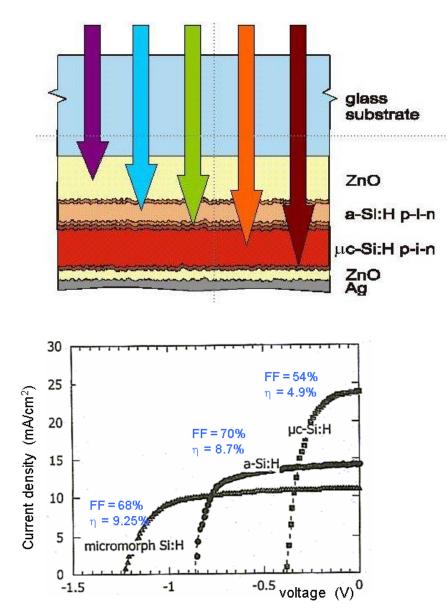


dilution ratio rH = ([H2] + [SiH4])/[SiH4].

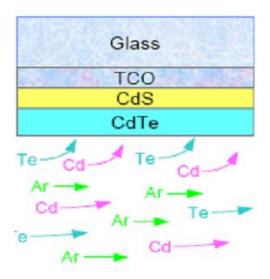
rH < 30, amorphous silicon growth rH > 45, crystalline layers are formed

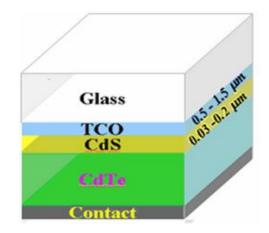
Tandem solar cell – "micromorph"(microcrystal + amorphous)





CdTe modules





Vapor Transport Deposition

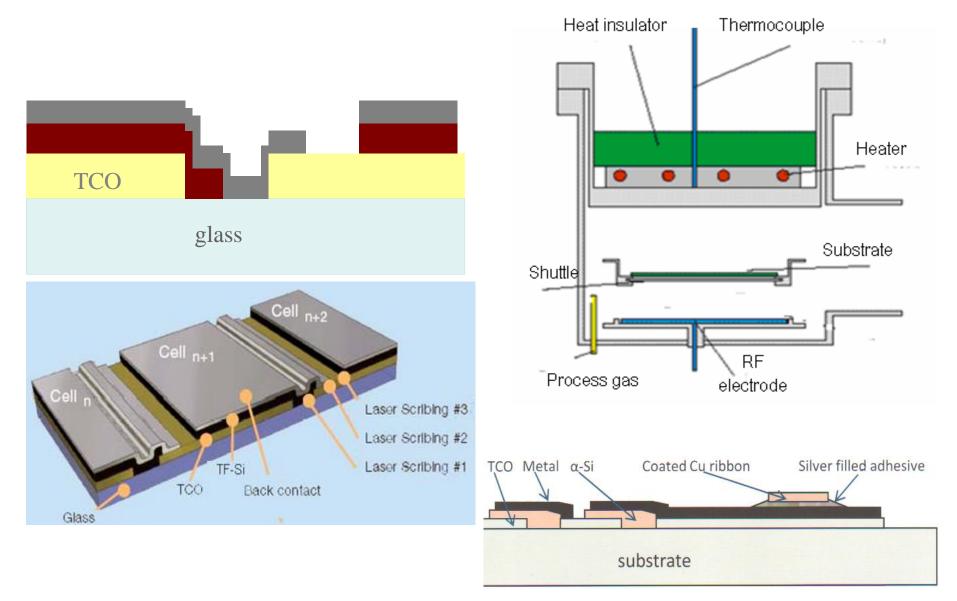
CdTe solar Cells

Low fabrication cost

Relatively high efficiency (10%)

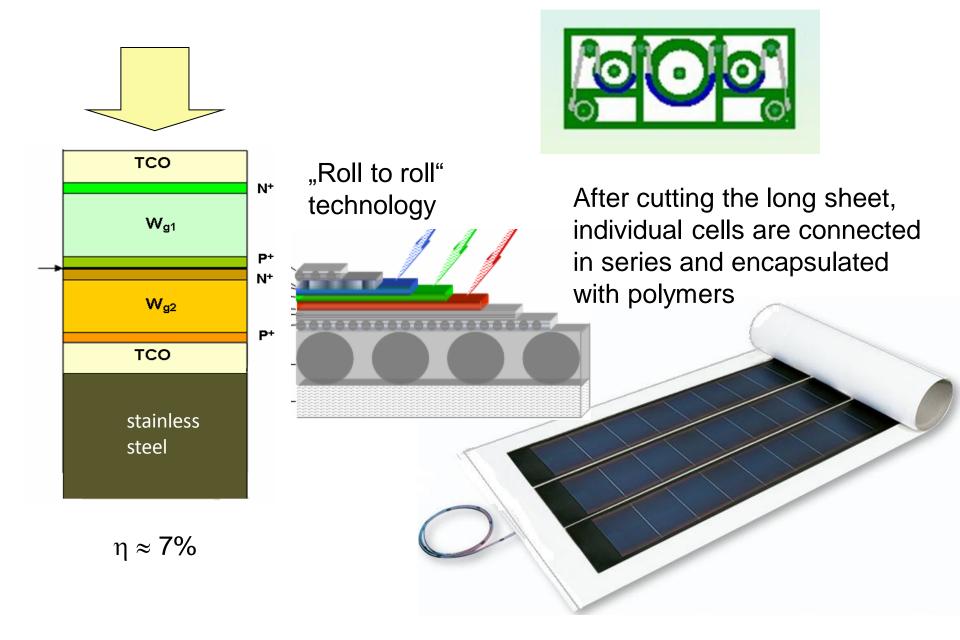
toxicity of Cd limited supply of Te

Thin-film modules on glass substrates

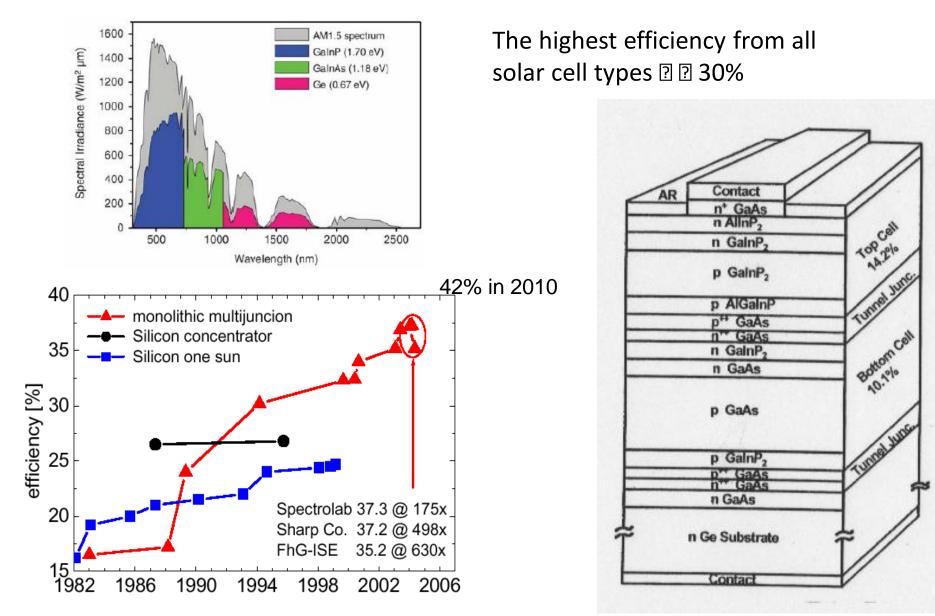


Back surface is laminated with EVA and suitable covering sheet (glass, tedlar)

Thin-film modules on metallic substrates

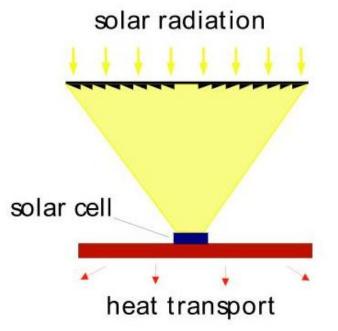


A^{III}B^V multijunction cells



High efficiency solar cell application

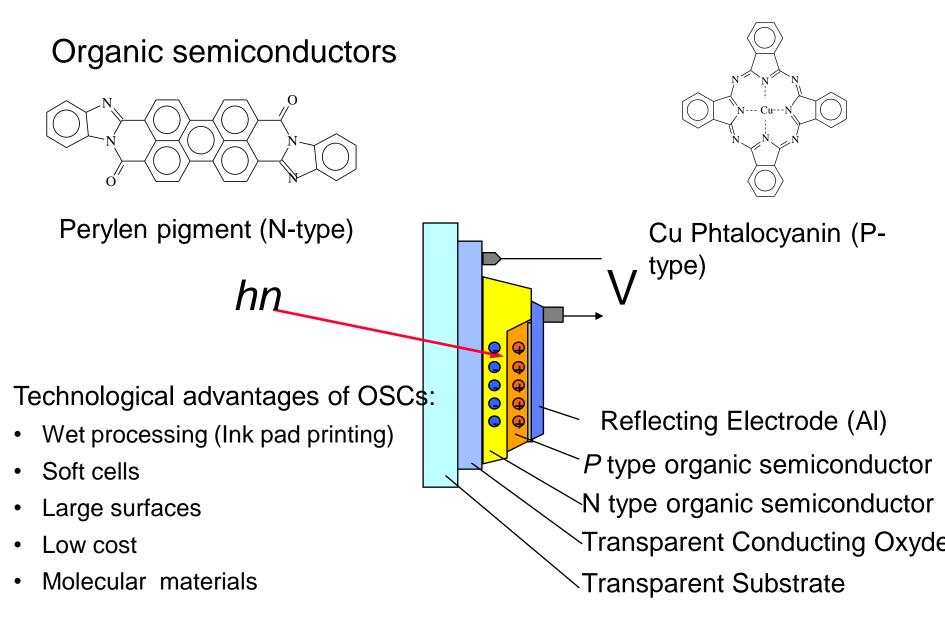
Concentrator modules

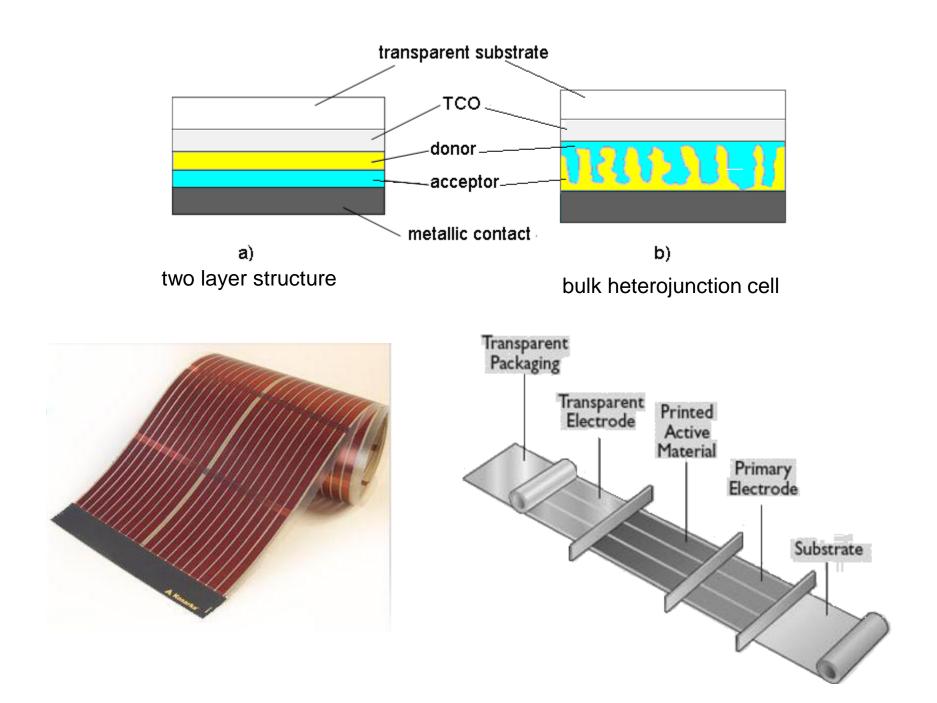


Cell	V _{OC} [mV]	1/V _{OC} dV _{OC} /dT [%/K]
Ge	200	-0.90
GaAs	1050	-0.19
GaInP	1350	-0.16
GaInP/GaAs	2400	-0.17
GaInP/GaAs/Ge	2600	-0.23
GaInP/GaAs/Ge (500 suns)	3080	-0.19



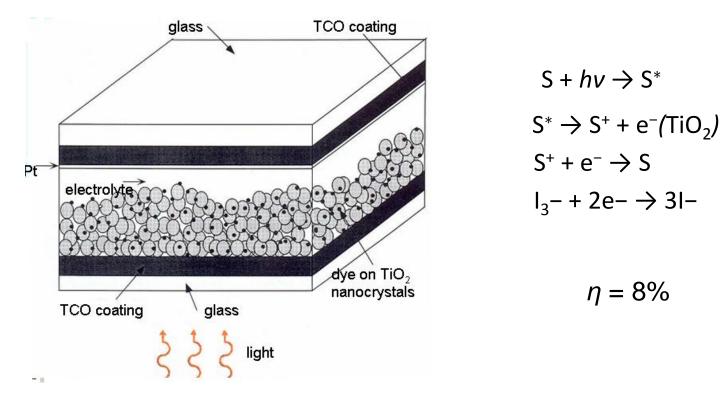
New solar cell concepts





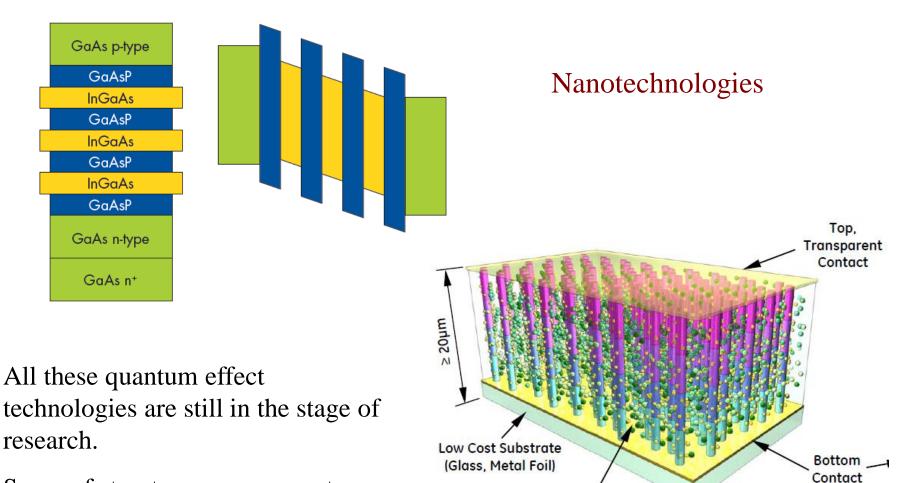
Dye-sensitized Solar Cells (DSSC)

In development since 1992 TiO₂ – Iodine system



Operating temperature problems

Quantum effect solar cells



Some of structures may come to development and comertional phase in a few years

